

HIGH-POWER PNP SILICON POWER TRANSISTORS

 \dots designed for use in general-purpose amplifier and switching application .

FEATURES:

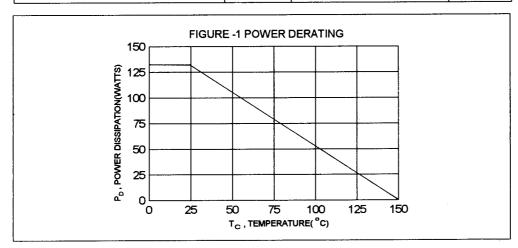
- * Recommend for 105W High Fiderity Audio Frequency Amplifier Output stage
- * Complementary to 2SC3519 & 2SC3519A

MAXIMUM RATINGS

Characteristic	Symbol	2SA1386	2SA1386A	Unit
Collector-Emitter Voltage	V _{CEO}	160	180	V
Collector-Base Voltage	V _{CBO}	160	180	٧
Emitter-Base Voltage	V _{EBO}	5.0		٧
Collector Current - Continuous - Peak	I _C	15 20		Α
Base current	I _B	4.0		A
Total Power Dissipation @T _C = 25°C Derate above 25°C	P _D	130 1.04		W/°C
Operating and Storage Junction Temperature Range	T _J ,T _{STG}	-55 to +150		°C

THERMAL CHARACTERISTICS

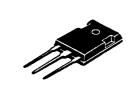
Characteristic	Symbol	Max	Unit
Thermal Resistance Junction to Case	Rθjc	0.961	°C/W



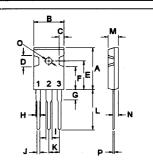
PNP 2SA1386 2SA1386A

15 AMPERE POWER TRANASISTOR

160 -180 VOLTS 130 WATTS



TO-247(3P)



PIN 1.BASE 2.COLLECTOR 3.EMITTER

DIM	MILLIMETERS			
Dille	MIN	MAX		
Α	20.63	22.38		
В	15.38	16.20		
С	1.90 2.70			
D	5.10 6.10			
E	14.81	15.22		
F	11.72	12.84		
G	4.20	4.50		
Н	1.82 2.46			
1	2.92	3.23		
J	0.89	1.53		
Κ	5.26	5.66		
L	18.50	21.50		
M	4.68	5.36		
N	2.40	2.80		
0	3.25	3.65		
Р	0.55	0.70		
TO-247(3P)				

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ELECTRICAL CHARACTERISTICS (T_c = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit		
OFF CHARACTERISTICS							
Collector-Emitter Breakdown Voltage (I _C = 25 mA, I _B = 0)	2SA1386 2SA1386A	V _{(BR)CEO}	160 180		V		
Collector Cutoff Current (V _{CB} = 160 V, I _E = 0) (V _{CB} = 180 V, I _E = 0)	2SA1386 2SA1386A	Ісво		100 100	uA		
Emitter Cutoff Current (V _{EB} = 5.0 V, I _C = 0)		I _{EBO}		100	uA		
ON CHARACTERISTICS (1)							
DC Current Gain (I _C = 5.0 A, V _{CE} = 4.0 V)		hFE	50				
Collector-Emitter Saturation Voltage (I _C = 5.0 A, I _B = 500 mA)		V _{CE(sat)}		2.0	V		
DYNAMIC CHARACTERISTICS							
Current-Gain-Bandwidth Product (I _C = 2.0 A, V _{CE} = 12 V, f = 1.0 MHz)		f _T	10		MHz		

0.30(typ)

0.75(typ)

0.25(typ)

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t s

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Turn-on Time

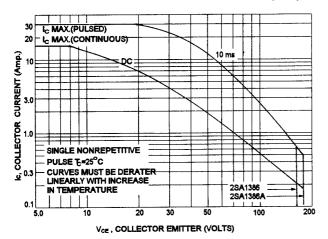
Storage Time

Fall Time

V_{CC}= 40 V, I_C= 10 A I_{B1}= -I_{B2}= 1.0 A R_L= 4 ohm

⁽¹⁾ Pulse Test: Pulse Width =300 us, Duty Cycle ≤ 2.0%

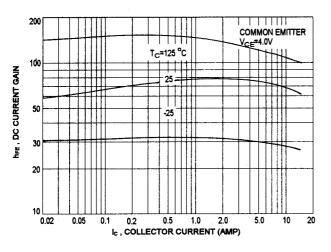
ACTIVE REGION SAFE OPERATING AREA (SOA)



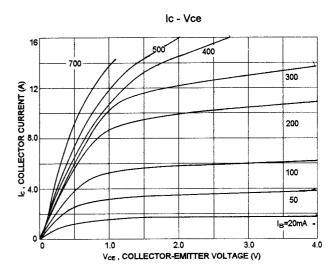
There are two limitation on the power handling ability of a transistor:average junction temperature and second breakdown safe operating area curves indicate $I_{\text{C}^{-}}V_{\text{CE}}$ limits of the transistor that must be observed for reliable operation i.e., the transistor must not be subjected to greater dissipation than curves indicate.

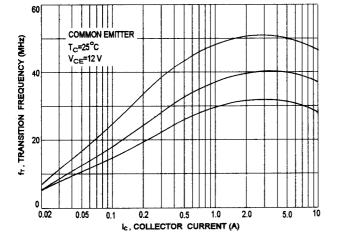
The data of SOA is base on $T_{J(PK)}$ =150 °C; T_C is variable depending on conditions.second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(PK)} \le 150$ °C, At high case temperatures, thermal limita tion will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

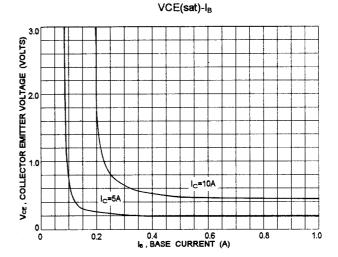




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